NSN 5962-01-116-8673

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View Online at https://aerobasegroup.com/nsn/5962-01-116-8673

Body Length:
Between 0.745 inches and 0.785 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.105 inches and 0.180 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Jss/rocc 05869
Features Provided:
Hermetically sealed and synchronous and expandable and low power and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
7 input
Case Outline Source And Designator:
Mo-001-ac joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
20.5 volts power source
Memory Device Type:
First-in first-out
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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